## NSN 5961-01-369-6766

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-369-6766 **Inclosure Material:** Ceramic **Overall Length:** Between 0.660 inches and 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** 0.325 inches **Component Name And Quantity:** 32 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 50.0 breakdown voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 100.00 milliamperes all primaries preset all semiconductor device diode **Power Rating Per Characteristic:** 450.0 milliwatts any acceptable preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0